RENESAS

RJK03N5DPA

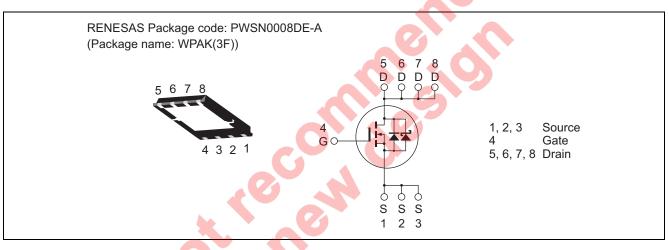
30V, 45A, 2.9mΩmax. Built in SBD N Channel Power MOS FET High Speed Power Switching

R07DS0786EJ0200 Rev.2.00 Feb 12, 2013

Features

- High speed switching
- Capable of 4.5 V gate drive
- Low drive current
- High density mounting
- Low on-resistance
- Pb-free
- Halogen-free

Outline



Absolute Maximum Ratings

		$(Ta = 25^{\circ}C)$			
Item	Symbol	Ratings	Unit		
Drain to source voltage	V _{DSS}	30	V		
Gate to source voltage	V _{GSS}	±20	V		
Drain current	ID	45	A		
Drain peak current	Note1 I _{D(pulse)}	180	A		
Body-drain diode reverse drain current	I _{DR}	45	A		
Avalanche current	I _{AP} Note 2	16	A		
Avalanche energy	E _{AS} Note 2	25.6	mJ		
Channel dissipation	Pch Note3	40	W		
Channel to case thermal impedance	θch-c ^{Note3}	3.13	°C/W		
Channel temperature	Tch	150	°C		
Storage temperature	Tstg	-55 to +150	۵°C		

Notes: 1. PW \leq 10 $\mu s,\,duty\,cycle \leq$ 1%

- 2. Value at Tch = 25°C, Rg \geq 50 Ω
- 3. Tc = 25°C

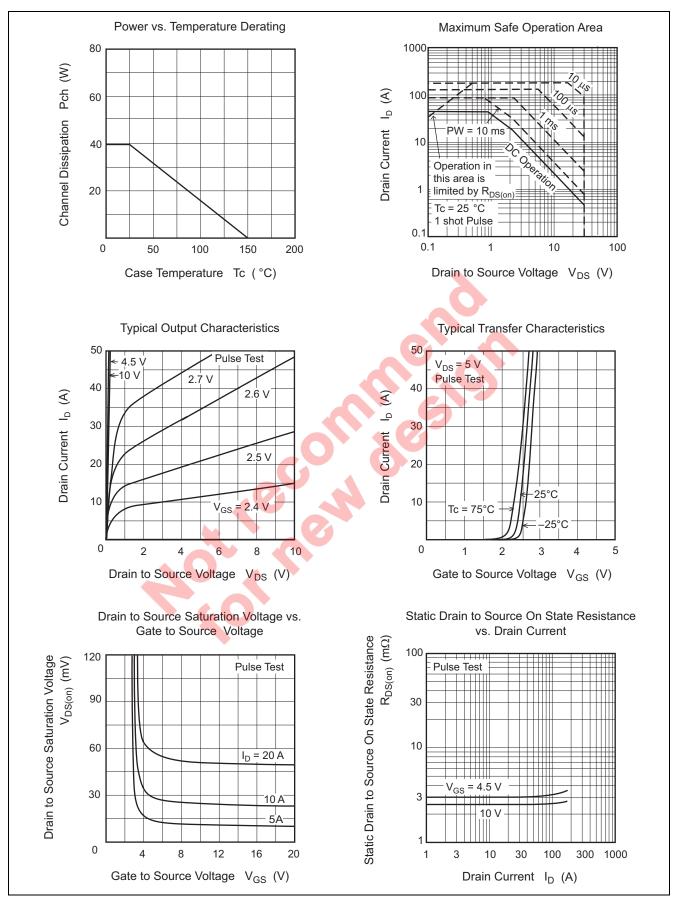


Electrical Characteristics

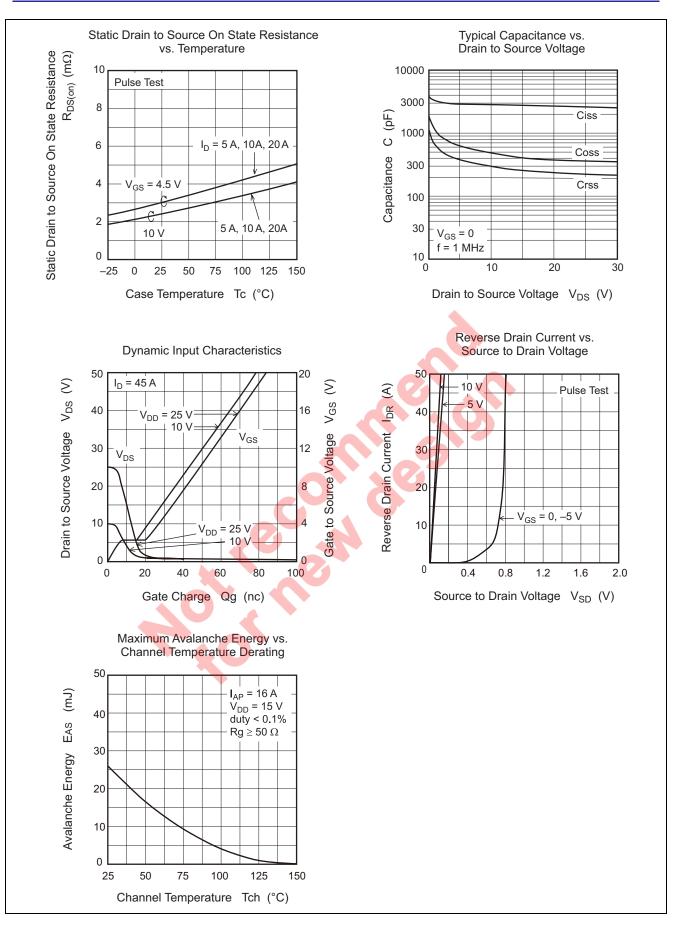
						$(Ta = 25^{\circ}C)$
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	V _{(BR)DSS}	30	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source leak current	I _{GSS}		_	± 0.5	μA	V _{GS} = ±20 V, V _{DS} = 0
Zero gate voltage drain current	I _{DSS}		_	1	mA	V _{DS} = 24 V, V _{GS} = 0
Gate to source cutoff voltage	V _{GS(off)}	1.2	—	2.5	V	V _{DS} = 10 V, I _D = 1 mA
Static drain to source on state	R _{DS(on)}	_	2.4	2.9	mΩ	I_D = 22.5A, V_{GS} = 10 V ^{Note4}
esistance	R _{DS(on)}	_	3.0	3.9	mΩ	I_D = 22.5A, V_{GS} = 4.5 V ^{Note4}
Forward transfer admittance	y _{fs}		100	_	S	I _D = 22.5A, V _{DS} = 5 V ^{Note4}
nput capacitance	Ciss	_	2870	4020	pF	V _{DS} = 10 V
Output capacitance	Coss	_	485	_	pF	V _{GS} = 0
Reverse transfer capacitance	Crss	_	300	_	pF	f = 1 MHz
Gate Resistance	Rg	_	1.5	3.0	Ω	
Total gate charge	Qg	_	23	_	nC	V _{DD} = 10 V
Gate to source charge	Qgs		7.9	_	nC	V _{GS} = 4.5 V
Gate to drain charge	Qgd	_	7.5	_	nC	I _D = 45 A
Turn-on delay time	t _{d(on)}	_	5.8	_	ns	V _{GS} = 10 V, I _D = 22.5A
Rise time	tr	_	3.4		ns	$V_{DD} \cong 10 \text{ V}$
Turn-off delay time	t _{d(off)}	_	49.9		ns	$R_L = 0.44\Omega$
Fall time	t _f	_	16.8	2	ns	Rg = 4.7 Ω
Body–drain diode forward voltage	V _{DF}		0.41	—	V	$I_{\rm F} = 2 \text{ A}, V_{\rm GS} = 0^{\rm Note4}$
Body–drain diode reverse recovery	t _{rr}		8.7	_	ns	I _F =45 A, V _{GS} = 0
ime				6		di _F / dt = 500 A/ µs
ime Notes: 4. Pulse test	505					

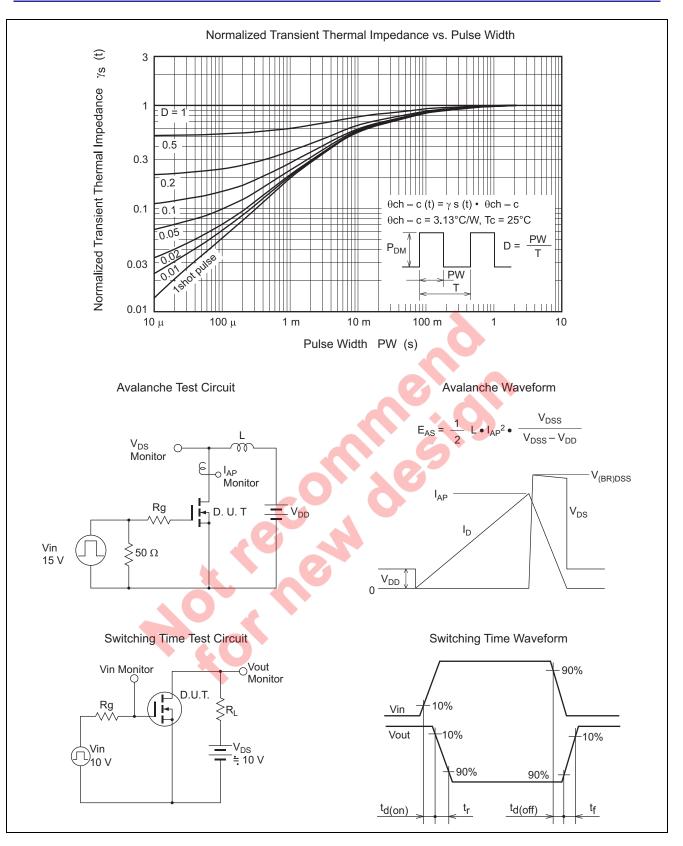


Main Characteristics



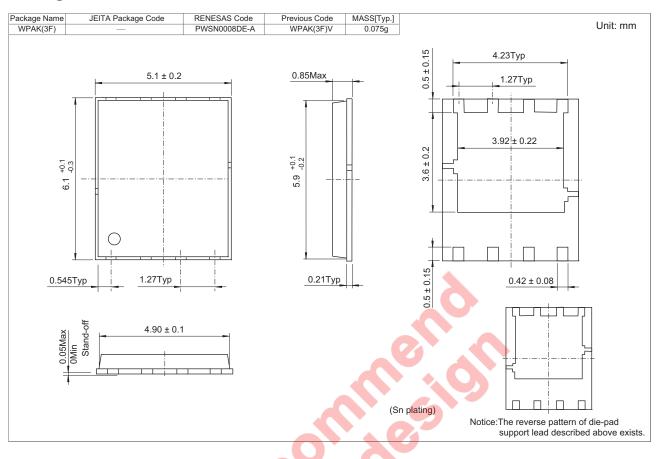








Package Dimensions



Ordering Information

Orderable Part Number	Quantity	Shipping Container	
RJK03N5DPA-00-J5A	3000 pcs	Taping	

Note: The symbol of 2nd "-" is occasionally presented as "#".

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